# <u>MOSFET</u> – P-Channel, Small Signal, SOT-563

# -20 V, -950 mA

# Features

- Low R<sub>DS(on)</sub> Improving System Efficiency
- Low Threshold Voltage
- Small Footprint 1.6 x 1.6 mm
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## Applications

- Load/Power Switches
- Battery Management
- Cell Phones, Digital Cameras, PDAs, Pagers, etc.

# **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted.)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V <sub>DSS</sub>	-20	V
Gate-to-Source Voltage			V <sub>GS</sub>	±8.0	V
Continuous Drain Current	Steady T <sub>A</sub> = 25°C		1-	-860	mA
(Note 1)	State	$T_A = 70^{\circ}C$	ID	-690	
Power Dissipation (Note 1)	Steady State		P <sub>D</sub>	170	mW
Continuous Drain Current	t≤5s	$T_A = 25^{\circ}C$	1-	-950	mA
(Note 1)	1 2 3 3	$T_A = 70^{\circ}C$	ID	-760	
Power Dissipation (Note 1)	t ≤ 5 s		P <sub>D</sub>	210	mW
Pulsed Drain Current	t <sub>p</sub> = 10 μs		I <sub>DM</sub>	-4.0	А
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C
Source Current (Body Diode)			IS	-360	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C	

## THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	720	°C/W
Junction–to–Ambient – $t \le 5 s$ (Note 1)	$R_{\theta JA}$	600	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface-mounted on FR4 board using 1 in. sq. pad size

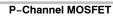
(Cu. area = 1.127 in. sq. [1 oz.] including traces).

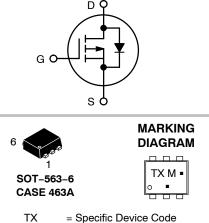


# **ON Semiconductor®**

# http://onsemi.com

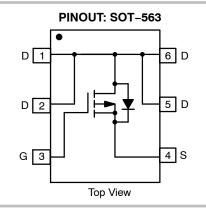
V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> Typ	I <sub>D</sub> Max
	120 mΩ @ -4.5 V	
–20 V	144 mΩ @ –2.5 V	–950 mA
	195 mΩ @ –1.8 V	





M = Date Code

= Pb-Free Package
(Note: Microdot may be in either location)



## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}C$ unless otherwise noted.)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, $I_{D}$ = -250 µA		-20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				-13		mV/°C
Zero Gate Voltage Drain Current		V <sub>GS</sub> = 0 V	$T_J = 25^{\circ}C$			-1.0	μA
	I <sub>DSS</sub>	$V_{DS} = -20 V$	T <sub>J</sub> = 125°C			-5.0	
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{DS}$ = 0 V, $V_{GS}$ = ±8.0 V				±100	nA
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D = -250 \ \mu A$		-0.45		-1.0	V
Negative Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				2.4		mV/°C
Drain-to-Source On Resistance		$V_{GS}$ = -4.5 V, I <sub>D</sub> = -950 mA			120	150	mΩ
		$V_{GS}$ = -4.5 V, I <sub>D</sub> = -770 mA			112	142	
	R <sub>DS(on)</sub>	$V_{GS}$ = -2.5 V, I <sub>D</sub> = -670 mA			144	200	
		$V_{GS}$ = -1.8 V, I <sub>D</sub> = -200 mA			195	240	
Forward Transconductance	<b>9</b> FS	$V_{DS} = -10 \text{ V}, \text{ I}_{D}$	= -810 mA		3.1		S
CHARGES AND CAPACITANCES							
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> = 0 V, f = 1.0 MHz, V <sub>DS</sub> = -16 V			458		pF
Output Capacitance	C <sub>OSS</sub>				61		1
Reverse Transfer Capacitance	C <sub>RSS</sub>				38		
Total Gate Charge	Q <sub>G(TOT)</sub>				5.6		nC
Threshold Gate Charge	Q <sub>G(TH)</sub>	V <sub>GS</sub> = –4.5 V, V <sub>E</sub> I <sub>D</sub> = –770	os = −10 V;		0.6		1
Gate-to-Source Charge	Q <sub>GS</sub>	ID = -110	111A		0.9		
Gate-to-Drain Charge	Q <sub>GD</sub>				1.2		
SWITCHING CHARACTERISTICS (Note	e 3)						
Turn-On Delay Time	t <sub>d(ON)</sub>				5.0		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = -4.5 V. Vr	ор = –10 V,		12		1
Turn-Off Delay Time	t <sub>d(OFF)</sub>	$V_{GS}$ = -4.5 V, $V_{DD}$ = -10 V, $I_{D}$ = -950 mA, $R_{G}$ = 6.0 $\Omega$			23.7		1
Fall Time	t <sub>f</sub>				18		1
DRAIN-SOURCE DIODE CHARACTER	ISTICS				-		-
Forward Diode Voltage		V <sub>GS</sub> = 0 V,	$T_J = 25^{\circ}C$		-0.64	-0.9	V
	V <sub>SD</sub>	$I_{\rm S} = -360  \rm{mA}$	T <sub>J</sub> = 125°C		-0.5		1

Reverse Recovery Time

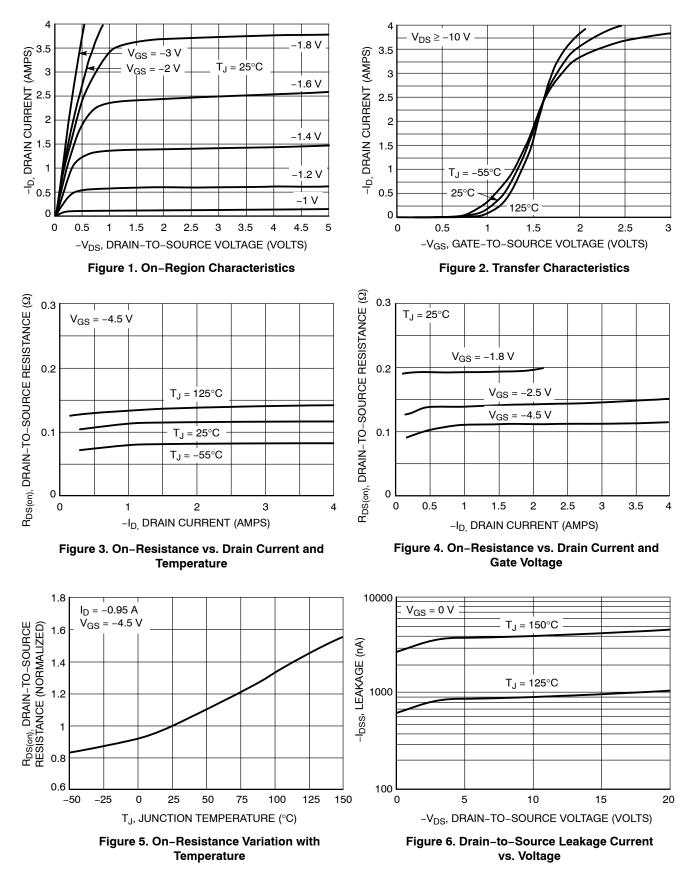
Pulse Test: pulse width ≤ 300 µs, duty cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.

t<sub>RR</sub>

 $\label{eq:VGS} \begin{array}{l} V_{GS} = 0 \ V, \ dI_S/dt = 100 \ A/\mu s, \\ I_S = -360 \ mA \end{array}$ 

10.5

ns



# TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

# TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = 25°C unless otherwise noted)

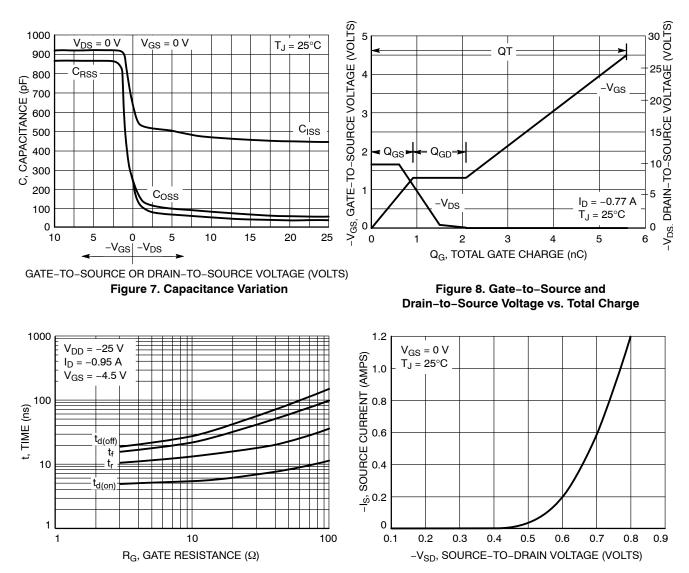


Figure 9. Resistive Switching Time Variation vs. Gate Resistance



## ORDERING INFORMATION

Device	Package	Shipping
NTZS3151PT1G	SOT-563 (Pb-Free)	4000 / Tape & Reel
NTZS3151PT1H	SOT-563 (Pb-Free)	4000 / Tape & Reel
NTZS3151PT5G	SOT-563 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

6Х





SOT-563, 6 LEAD CASE 463A ISSUE H

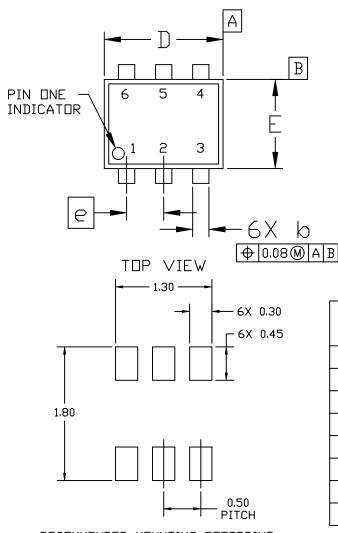
DATE 26 JAN 2021

ALE 4:1

NDTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.

А

- 1. DIMENSIONING AND TOLERANCING PER A 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS DF BASE MATERIAL.



SIDE VIEW MILLIMETERS DIM MIN. NDM. MAX. 0.50 0.55 0.60 Α 0.17 0.22 0.27 b 0.08 0.13 0.18 С 1.50 1.60 1.70 D Ε 1.10 1.20 1.30 0.50 BSC e L 0.10 0.20 0.30  $\mathsf{H}_\mathsf{E}$ 1.50 1.60 1.70

 $\overline{}$ 

RECOMMENDED MOUNTING FOOTPRINT\* \* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

	98AON11126D Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION: SOT-563, 6 LEAD	PAGE 1 OF 2		

ON Semiconductor and unarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights or the rights of others.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. EMITTER 1	PIN 1. EMITTER 1	PIN 1. CATHIDE 1
2. BASE 1	2. EMITTER 2	2. CATHIDE 1
3. COLLECTOR 2	3. BASE 2	3. ANUDE/ANUDE 2
4. EMITTER 2	4. COLLECTOR 2	4. CATHIDE 2
5. BASE 2	5. BASE 1	5. CATHIDE 2
6. COLLECTOR 1	6. COLLECTOR 1	6. ANUDE/ANUDE 1
STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. COLLECTOR	PIN 1. CATHEDE	PIN 1. CATHODE
2. COLLECTOR	2. CATHEDE	2. ANODE
3. BASE	3. ANEDE	3. CATHODE
4. EMITTER	4. ANEDE	4. CATHODE
5. COLLECTOR	5. CATHEDE	5. CATHODE
6. COLLECTOR	6. CATHEDE	6. CATHODE
STYLE 7:	STYLE 8:	STYLE 9:
PIN 1. CATHODE	PIN 1. DRAIN	PIN 1. SDURCE 1
2. ANODE	2. DRAIN	2. GATE 1
3. CATHODE	3. GATE	3. DRAIN 2
4. CATHODE	4. SDURCE	4. SDURCE 2
5. ANODE	5. DRAIN	5. GATE 2
6. CATHODE	6. DRAIN	6. DRAIN 1
STYLE 10: PIN 1. CATHIDE 1 2. N/C 3. CATHIDE 2 4. ANIDE 2 5. N/C C ANIDE 1	STYLE 11: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	

6. COLLECTOR 2

DATE 26 JAN 2021

# GENERIC **MARKING DIAGRAM\***



XX = Specific Device Code

M = Month Code

. = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON11126D Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOT-563, 6 LEAD		PAGE 2 OF 2	

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights or the rights of others.

4. ANDDE 2 5. N/C 6. ANDDE 1

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Onsemi: NTZS3151PT1G NTZS3151PT5G